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LMH0002 SMPTE 292M / 259M Serial Digital Cable Driver

Check for Samples: LMH0002

FEATURES

- SMPTE 292M, SMPTE 344M and SMPTE 259M Compliant
- Supports DVB-ASI at 270 Mbps
- Data Rates to 1.485 Gbps
- Differential Input
- 75Ω Differential Output
- Selectable Slew Rate
- Adjustable Output Amplitude
- Single 3.3V Supply Operation
- Operating Temperature Range: Commercial 0°C to +70°C (LMH0002MA) or Industrial -40°C to +85°C (LMH0002TMA and LMH0002SQ)
- Typical Power Consumption: 125 mW in SD Mode and 149 mW in HD Mode
- 8-pin SOIC or 16-pin WQFN Package
- Replaces the GS1528, GS1528A, or GS1578A

APPLICATIONS

- SMPTE 292M, SMPTE 344M, and SMPTE 259M Serial Digital Interfaces
- Sonet/SDH and ATM Interfaces
- Digital Routers and Switches
- Distribution Amplifiers
- Buffer Applications
- Set Top Boxes
- Security Cameras

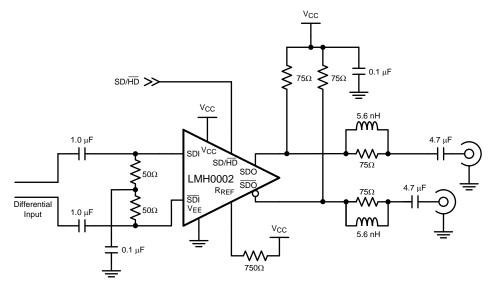
DESCRIPTION

The LMH0002 SMPTE 292M / 259M serial digital cable driver is a monolithic, high-speed cable driver designed for use in SMPTE 292M / 259M serial digital video and ITU-T G.703 serial digital data transmission applications. The LMH0002 drives 75 Ω transmission lines (Belden 8281, Belden 1694A or equivalent) at data rates up to 1.485 Gbps.

The LMH0002 provides two selectable slew rates for SMPTE 259M and SMPTE 292M compliance. The output voltage swing is adjustable via a single external resistor.

The LMH0002 is powered from a single 3.3V supply. Power consumption is typically 125 mW in SD mode and 149 mW in HD mode. The LMH0002 is available in an 8-pin SOIC or 16-pin WQFN package.

Typical Application



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LMH0002

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RUMENTS

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾

Supply Voltage:	-0.5V to 3.6V
Input Voltage (all inputs)	-0.3V to V _{CC} +0.3V
Output Current	28 mA
Storage Temperature Range	−65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (Soldering 4 Sec)	+260°C
Package Thermal Resistance $ extsf{ heta_J_A}$ 8-pin SOIC $ extsf{ heta_J_A}$ 16-pin WQFN $ extsf{ heta_J_C}$ 8-pin SOIC $ extsf{ heta_J_C}$ 16-pin WQFN	+160°C/W +78.9°C/W +105°C/W +42.7°C/W
ESD Rating (HBM)	5kV
ESD Rating (MM)	250V

(1) "Absolute Maximum Ratings" are those parameter values beyond which the life and operation of the device cannot be ensured. The stating herein of these maximums shall not be construed to imply that the device can or should be operated at or beyond these values. The table of Electrical Characteristics specifies acceptable device operating conditions.

Recommended Operating Conditions

Supply Voltage (V _{CC} – V _{EE}):	3.3V ±5%
Operating Free Air Temperature (T _A) LMH0002MA LMH0002TMA and LMH0002SQ	0°C to +70°C −40°C to +85°C

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DC Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified⁽¹⁾⁽²⁾.

Symbol	Parameter	Conditions	Reference	Min	Тур	Max	Units
V _{CMIN}	Input Common Mode Voltage		SDI, <u>SDI</u>	1.6 + V _{SDI} /2		V _{CC} – V _{SDI} /2	V
V _{SDI}	Input Voltage Swing	Differential		100		2000	mV_{P-P}
V _{CMOUT}	Output Common Mode Voltage		SDO, SDO		V _{CC} – V _{SDO}		V
V_{SDO}	Output Voltage Swing	Single-ended, 75 Ω load, R _{REF} = 750 Ω 1%		750	800	850	mV _{P-P}
		Single-ended, 75 Ω load, R _{REF} = 590 Ω 1%		900	1000	1100	mV _{P-P}
	SD/HD Input Voltage	Min for SD	SD/HD	2.4			V
		Max for HD				0.8	V
	SD/HD Input Current				3.7		μA
I _{CC}	Supply Current	$SD/\overline{HD} = 0^{(3)}$			45	49	mA
		$SD/\overline{HD} = 1^{(3)}$			38	43	mA

(1) Current flow into device pins is defined as positive. Current flow out of device pins is defined as negative. All voltages are stated referenced to $V_{EE} = 0$ Volts.

Typical values are stated for V_{CC} = +3.3V and T_A = +25°C. (2)

Maximum I_{CC} is measured at V_{CC} = +3.465V and T_A = +70°C. (3)

AC Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified⁽¹⁾.

Symbol	Parameter	Conditions	Reference	Min	Тур	Max	Units
DR _{SDI}	Input Data Rate	(2)	SDI, SDI			1485	Mbps
t _{jit}	Additive Jitter	1.485 Gbps	SDO, SDO		26		ps _{P-P}
		270 Mbps			18		ps _{P-P}
t _r ,t _f	Output Rise Time, Fall Time	SD/HD = 0, 20% - 80%, ⁽³⁾			120	220	ps
		SD/HD = 1, 20% - 80%		400	560	800	ps
	Mismatch in Rise/Fall Time	(2)				30	ps
	Duty Cycle Distortion	SD/HD = 0, ⁽²⁾				30	ps
		SD/HD = 1, ⁽²⁾				100	ps
t _{OS}	Output Overshoot	(2)				8	%
RL _{SDO}	Output Return Loss	(4)		15	20		dB

(1)

(2)

Typical values are stated for $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$. Specification is ensured by characterization. Specification is ensured by characterization and verified by test. (3)

(4) Output return loss is dependent on board design. The LMH0002 meets this specification on the SD002 evaluation board from 5MHz to 1.5ĠHz.

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CONNECTION DIAGRAM

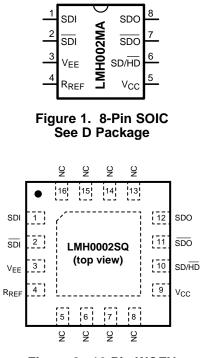


Figure 2. 16-Pin WQFN See RUM0016A Package

Table 1. PIN DESCRIPTIONS

SOIC Pin #	WQFN Pin #	Name	Description
1	1	SDI	Serial data true input.
2	2	SDI	Serial data complement input.
3	3	V _{EE}	Negative power supply (ground).
4	4	R _{REF}	Output driver level control. Connect a resistor to V_{CC} to set output voltage swing.
5	9	V _{CC}	Positive power supply (+3.3V).
6	10	SD/HD	Output slew rate control. Output rise/fall time complies with SMPTE 292M when low and SMPTE 259M when high.
7	11	SDO	Serial data complement output.
8	12	SDO	Serial data true output.
_	5, 6, 7, 8, 13, 14, 15, 16	NC	No connect.
_	DAP	V _{EE}	Connect exposed DAP to negative power supply (ground).

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APPLICATION INFORMATION

Device Operation

INPUT INTERFACING

The LMH0002 accepts either differential or single-ended input. The inputs are self-biased, allowing for simple AC or DC coupling. DC-coupled inputs must be kept within the specified common-mode range. SDI and <u>SDI</u> are self-biased at approximately 2.1V with $V_{CC} = 3.3V$. Figure 3 shows the differential input stage for SDI and <u>SDI</u>.

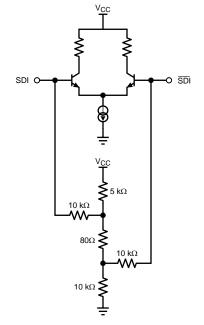


Figure 3. Differential Input Stage for SDI and SDI.

OUTPUT INTERFACING

The LMH0002 uses current mode outputs. Single-ended output levels are 800 mV_{P-P} into 75 Ω AC-coupled coaxial cable (with R_{REF} = 750 Ω). Output level is controlled by the value of the R_{REF} resistor connected between the R_{REF} pin and V_{CC}.

The R_{REF} resistor should be placed as close as possible to the R_{REF} pin. In addition, the copper in the plane layers below the R_{REF} network should be removed to minimize parasitic capacitance.

OUTPUT SLEW RATE CONTROL

The LMH0002 output rise and fall times are selectable for either SMPTE 259M or SMPTE 292M compliance via the SD/HD pin. For slower rise and fall times, or SMPTE 259M compliance, SD/HD is set high. For faster rise and fall times, or SMPTE 292M compliance, SD/HD is set low.

REPLACING THE GENNUM GS1528, GS1528A, and GS1578A

The LMH0002MA is form-fit-function compatible with the Gennum GS1528 and GS1528A. The LMH0002SQ is form-fit-function compatible with the Gennum GS1578A.

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REVISION HISTORY

Changes from Revision D (April 2013) to Revision E						
•	Changed layout of National Data Sheet to TI format	5				



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17-Mar-2017

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMH0002MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L002	Samples
LMH0002MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L002	Samples
LMH0002SQ/NOPB	ACTIVE	WQFN	RUM	16	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		L002	Samples
LMH0002SQ/S250	ACTIVE	WQFN	RUM	16	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		L002	Samples
LMH0002SQE/NOPB	ACTIVE	WQFN	RUM	16	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		L002	Samples
LMH0002SQX/NOPB	ACTIVE	WQFN	RUM	16	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		L002	Samples
LMH0002TMA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L002T	Samples
LMH0002TMAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L002T	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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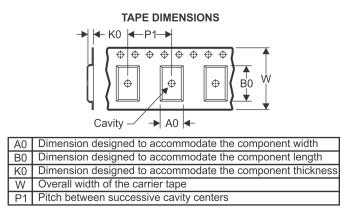
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH0002MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMH0002SQ/NOPB	WQFN	RUM	16	1000	178.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
LMH0002SQ/S250	WQFN	RUM	16	250	178.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
LMH0002SQE/NOPB	WQFN	RUM	16	250	178.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
LMH0002SQX/NOPB	WQFN	RUM	16	4500	330.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
LMH0002TMAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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PACKAGE MATERIALS INFORMATION

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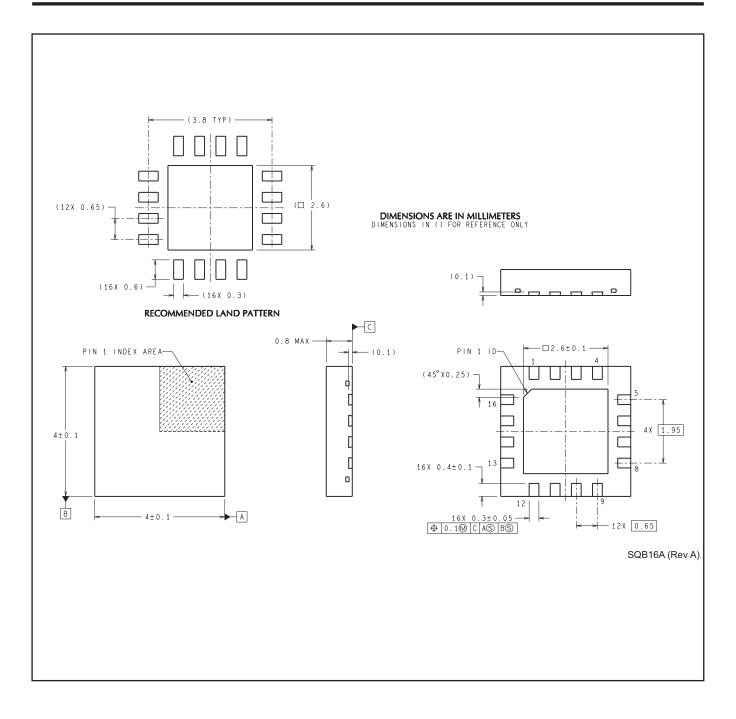


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH0002MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMH0002SQ/NOPB	WQFN	RUM	16	1000	210.0	185.0	35.0
LMH0002SQ/S250	WQFN	RUM	16	250	210.0	185.0	35.0
LMH0002SQE/NOPB	WQFN	RUM	16	250	210.0	185.0	35.0
LMH0002SQX/NOPB	WQFN	RUM	16	4500	367.0	367.0	35.0
LMH0002TMAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

MECHANICAL DATA

RUM0016A





D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.

